TOSHIBA CMOS Digital Integrated Circuit Silicon Monolithic

# TC74HC251AP,TC74HC251AF

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8-Channel Multiplexer (3-state)
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The TC74HC251A is a high speed CMOS 8-CHANNEL MULTIPLEXER fabricated with silicon gate C<sup>2</sup>MOS technology.

It achieves the high speed operation similar to equivalent LSTTL while maintaining the CMOS low power dissipation.

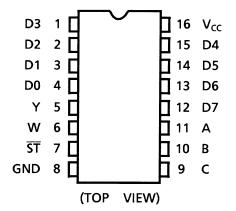
One of eight date input signals (D0-D7) is selected by decoding of the address input (A, B, C). The selected data appears on two outputs; non-inverting (Y) and inverting (W). When the strobe input is held high, both outputs are in the high-impedance state.

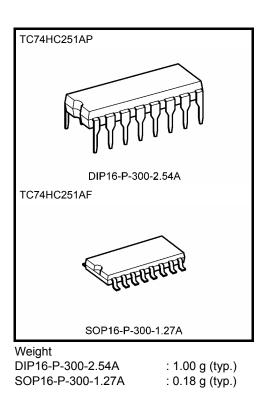
All inputs are equipped with protection circuits against static discharge or transient excess voltage.

#### Features

- High speed:  $t_{pd} = 15 \text{ ns}$  (typ.) at  $V_{CC} = 5 \text{ V}$
- Low power dissipation:  $I_{CC} = 4 \ \mu A \ (max)$  at  $Ta = 25^{\circ}C$
- High noise immunity:  $V_{\text{NIH}} = V_{\text{NIL}} = 28\% V_{\text{CC}}$  (min)
- Output drive capability: 10 LSTTL loads
- Symmetrical output impedance: |IOH| = IOL = 4 mA (min)
- Balanced propagation delays:  $t_{pLH} \simeq t_{pHL}$
- Wide operating voltage range:  $V_{CC}$  (opr) = 2~6 V
- Pin and function compatible with 74LS251

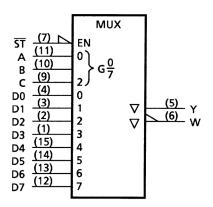
### **Pin Assignment**





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### **IEC Logic Symbol**



#### **Truth Table**

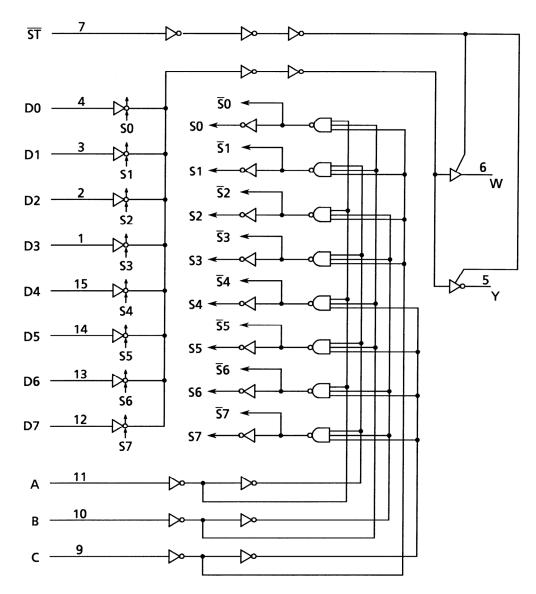
|        | h | Outputs |        |    |    |
|--------|---|---------|--------|----|----|
| Select |   |         | Strobe | v  | w  |
| С      | В | А       | ST     | Y  | vv |
| Х      | Х | Х       | Н      | Z  | Z  |
| L      | L | L       | L      | D0 | D0 |
| L      | L | н       | L      | D1 | D1 |
| L      | н | L       | L      | D2 | D2 |
| L      | н | н       | L      | D3 | D3 |
| н      | L | L       | L      | D4 | D4 |
| н      | L | н       | L      | D5 | D5 |
| н      | н | L       | L      | D6 | D6 |
| н      | Н | Н       | L      | D7 | D7 |

X: Don't care

H: High impedance

### **TOSHIBA**

### System Diagram



#### Absolute Maximum Ratings (Note 1)

| Characteristics                    | Symbol           | Rating                       | Unit |  |
|------------------------------------|------------------|------------------------------|------|--|
| Supply voltage range               | V <sub>CC</sub>  | -0.5~7                       | V    |  |
| DC input voltage                   | V <sub>IN</sub>  | -0.5~V <sub>CC</sub> + 0.5   | V    |  |
| DC output voltage                  | V <sub>OUT</sub> | -0.5~V <sub>CC</sub> + 0.5   | V    |  |
| Input diode current                | I <sub>IK</sub>  | ±20                          | mA   |  |
| Output diode current               | IOK              | ±20                          | mA   |  |
| DC output current                  | IOUT             | ±25                          | mA   |  |
| DC V <sub>CC</sub> /ground current | ICC              | ±50                          | mA   |  |
| Power dissipation                  | PD               | 500 (DIP) (Note 2)/180 (SOP) | mW   |  |
| Storage temperature                | T <sub>stg</sub> | -65~150                      | °C   |  |

Note 1: Exceeding any of the absolute maximum ratings, even briefly, lead to deterioration in IC performance or even destruction.

Using continuously under heavy loads (e.g. the application of high temperature/current/voltage and the significant change in temperature, etc.) may cause this product to decrease in the reliability significantly even if the operating conditions (i.e. operating temperature/current/voltage, etc.) are within the absolute maximum ratings and the operating ranges.

Please design the appropriate reliability upon reviewing the Toshiba Semiconductor Reliability Handbook ("Handling Precautions"/"Derating Concept and Methods") and individual reliability data (i.e. reliability test report and estimated failure rate, etc).

Note 2: 500 mW in the range of  $Ta = -40 \sim 65^{\circ}$ C. From Ta = 65 to  $85^{\circ}$ C a derating factor of -10 mW/°C shall be applied until 300 mW.

| Characteristics          | Symbol                          | Rating                           | Unit |
|--------------------------|---------------------------------|----------------------------------|------|
| Supply voltage           | V <sub>CC</sub>                 | 2~6                              | V    |
| Input voltage            | V <sub>IN</sub>                 | 0~V <sub>CC</sub>                | V    |
| Output voltage           | V <sub>OUT</sub>                | 0~V <sub>CC</sub>                | V    |
| Operating temperature    | T <sub>opr</sub>                | -40~85                           | °C   |
|                          |                                 | 0~1000 (V <sub>CC</sub> = 2.0 V) |      |
| Input rise and fall time | t <sub>r</sub> , t <sub>f</sub> | $0 \sim 500 (V_{CC} = 4.5 V)$    | ns   |
|                          |                                 | 0~400 (V <sub>CC</sub> = 6.0 V)  |      |

#### **Operating Ranges (Note)**

Note: The operating ranges must be maintained to ensure the normal operation of the device. Unused inputs must be tied to either VCC or GND.

#### **Electrical Characteristics**

#### **DC Characteristics**

|                              |                 | Test Condition   |                           | Ta = 25°C              |      |      | Ta = −40~85°C |      |      |      |  |
|------------------------------|-----------------|--|---------------------------|------------------------|------|------|---------------|------|------|------|--|
| Characteristics Symbol       |                 |  |                           | V <sub>CC</sub><br>(V) | Min  | Тур. | Max           | Min  | Max  | Unit |  |
| High-level input<br>voltage  | VIH             | —  |                           | 2.0                    | 1.50 | _    | _             | 1.50 | _    |      |  |
|                              |                 |  |                           | 4.5                    | 3.15 | —    | —             | 3.15 | —    | V    |  |
|                              |                 |  |                           | 6.0                    | 4.20 | —    | —             | 4.20 |      |      |  |
|                              |                 |  |                           |                        | —    | —    | 0.50          | —    | 0.50 |      |  |
| Low-level input<br>voltage   | VIL             | _  |                           | 4.5                    | —    |      | 1.35          | —    | 1.35 | V    |  |
| Ĵ                            |                 |  |                           | 6.0                    | _    |      | 1.80          | —    | 1.80 |      |  |
|                              | V <sub>OH</sub> | V <sub>IN</sub><br>= V <sub>IH</sub> or<br>V <sub>IL</sub>                 |                           | 2.0                    | 1.9  | 2.0  | —             | 1.9  | —    |      |  |
| High-level output<br>voltage |                 |  | I <sub>OH</sub> = -20 μA  | 4.5                    | 4.4  | 4.5  | —             | 4.4  | —    |      |  |
|                              |                 |  |                           | 6.0                    | 5.9  | 6.0  | —             | 5.9  |      | V    |  |
|                              |                 |  | I <sub>OH</sub> = -4 mA   | 4.5                    | 4.18 | 4.31 | —             | 4.13 | —    |      |  |
|                              |                 |  | I <sub>OH</sub> = -5.2 mA | 6.0                    | 5.68 | 5.80 | —             | 5.63 | —    |      |  |
|                              | V <sub>OL</sub> | V <sub>IN</sub><br>= V <sub>IH</sub> or<br>V <sub>IL</sub>                 | $I_{OL} = 20 \ \mu A$     | 2.0                    | _    | 0.0  | 0.1           | _    | 0.1  |      |  |
|                              |                 |  |                           | 4.5                    | —    | 0.0  | 0.1           | —    | 0.1  |      |  |
| Low-level output<br>voltage  |                 |  |                           | 6.0                    | _    | 0.0  | 0.1           | —    | 0.1  | V    |  |
|                              |                 |  | I <sub>OL</sub> = 4 mA    | 4.5                    | _    | 0.17 | 0.26          | _    | 0.33 |      |  |
|                              |                 |  | I <sub>OL</sub> = 5.2 mA  | 6.0                    | _    | 0.18 | 0.26          | —    | 0.33 | l    |  |
| 3-state off leak<br>current  | I <sub>OZ</sub> | $V_{IN} = V_{IH} \text{ or } V_{IL}$<br>$V_{OUT} = V_{CC} \text{ or } GND$ |                           | 6.0                    |      | _    | ±0.5          | _    | ±5.0 | μΑ   |  |
| Input leakage<br>current     | I <sub>IN</sub> | $V_{IN} = V_{CC}$ or GND   |                           | 6.0                    |      | _    | ±0.1          | _    | ±1.0 | μΑ   |  |
| Quiescent supply current     | ICC             | $V_{IN} = V_{CC}$ or GND   |                           | 6.0                    |      |      | 4.0           |      | 40.0 | μΑ   |  |

#### AC Characteristics (C<sub>L</sub> = 15 pF, V<sub>CC</sub> = 5 V, Ta = 25°C, input: $t_r = t_f = 6$ ns)

| Characteristics            | Symbol           | Test Condition |   | Тур. | Max | Unit |
|----------------------------|------------------|----------------|---|------|-----|------|
| Output transition time     | t <sub>TLH</sub> |                |   | 4    | 8   | ns   |
|                            | t <sub>THL</sub> |                |   |      |     | 113  |
| Propagation delay time     | t <sub>pLH</sub> |                |   | 14   | 24  | 20   |
| (D-Y)                      | t <sub>pHL</sub> | —              |   | 14   | 24  | ns   |
| Propagation delay time     | t <sub>pLH</sub> |                | _ | 15   | 24  | 20   |
| (D-W)                      | t <sub>pHL</sub> |                |   |      |     | ns   |
| Propagation delay time     | t <sub>pLH</sub> |                | — | 19   | 31  | ns   |
| (A, B, C-Y)                | t <sub>pHL</sub> |                |   |      |     | 115  |
| Propagation delay time     | t <sub>pLH</sub> | —              |   | 19   | 31  |      |
| (A, B, C-W)                | t <sub>pHL</sub> |                |   |      |     | ns   |
| 3-state output enable time | t <sub>pZL</sub> |                |   | 10   | 18  | 20   |
|                            | t <sub>pZH</sub> | _              |   | 10   | 18  | ns   |

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#### Ta = 25°C Ta = -40~85°C **Test Condition** Characteristics Symbol Unit Vcc Min Тур. Max Min Max (V) 2.0 30 75 95 \_\_\_\_ \_\_\_\_ t<sub>TLH</sub> Output transition time 4.5 8 15 19 ns \_\_\_\_ \_\_\_\_ **t**THL 7 6.0 13 16 2.0 65 140 175 Propagation delay \_\_\_\_ \_\_\_\_ tpLH time 4.5 17 28 35 ns \_\_\_\_ \_\_\_\_ tpHL (D-Y) 6.0 14 24 30 \_\_\_\_ \_\_\_\_ 2.0 70 140 175 Propagation delay tpLH time 4.5 18 28 35 ns \_\_\_\_ \_\_\_\_ tpHL (D-W) 6.0 15 24 30 \_\_\_\_ \_ 2.0 80 180 225 Propagation delay t<sub>pLH</sub> time 4.5 23 36 45 ns \_\_\_\_ \_\_\_\_ tpHL (A, B, C-Y) 6.0 \_\_\_\_ 19 31 \_\_\_\_ 38 2.0 80 180 225 \_\_\_\_ Propagation delay t<sub>pLH</sub> time 4.5 23 36 45 ns \_\_\_\_ tpHL (A, B, C-W) 6.0 19 31 38 \_\_\_\_ \_\_\_\_ 2.0 40 105 130 3-state output enable tpZL 4.5 13 21 26 ns \_\_\_\_ time t<sub>pZH</sub> 6.0 10 19 22 2.0 25 105 130 \_\_\_\_ \_\_\_\_ tpLZ 3-state output disable 26 4.5 13 21 ns \_\_\_\_ \_\_\_\_ time t<sub>pHZ</sub> 6.0 11 19 22 Input capacitance 5 10 10 CIN \_\_\_\_ \_\_\_\_ pF \_\_\_\_ CPD Power dissipation pF 69 \_\_\_\_ \_\_\_\_ \_\_\_\_ capacitance (Note)

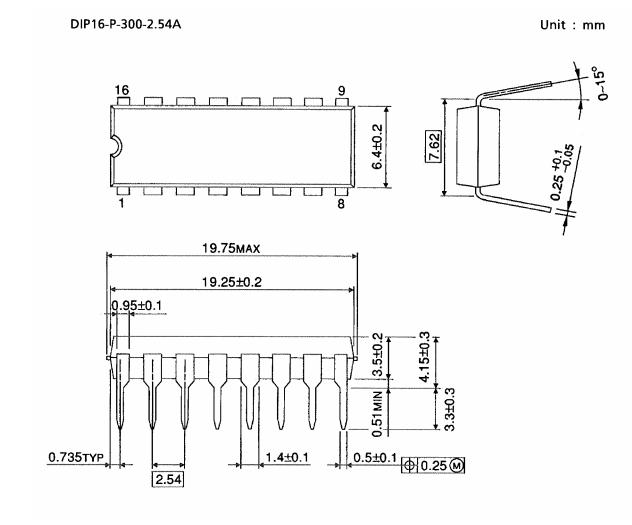
#### AC Characteristics ( $C_L = 50 \text{ pF}$ , input: $t_r = t_f = 6 \text{ ns}$ )

Note: C<sub>PD</sub> is defined as the value of the internal equivalent capacitance which is calculated from the operating current consumption without load.

Average operating current can be obtained by the equation:

 $I_{CC}$  (opr) =  $C_{PD} \cdot V_{CC} \cdot f_{IN} + I_{CC}$ 

#### **Package Dimensions**



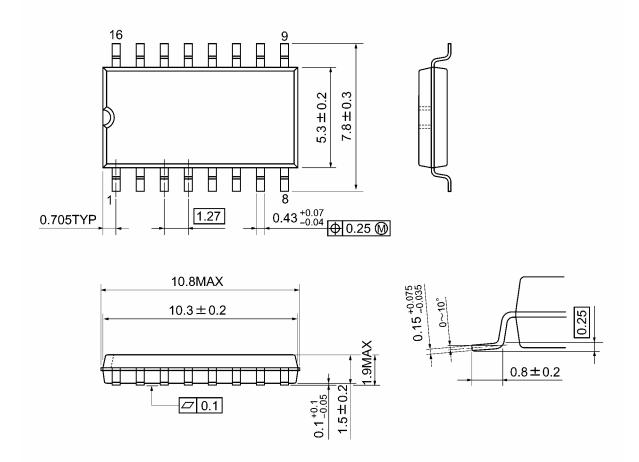
Weight: 1.00 g (typ.)



#### **Package Dimensions**

SOP16-P-300-1.27A

Unit: mm



Weight: 0.18 g (typ.)

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20070701-EN GENERAL

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